

SANYO	No. 1778B	DM1620
		LIQUID CRYSTAL DOT MATRIX DISPLAY MODULE 16 characters x 2 lines

General Description

The DM1620 is a liquid crystal dot matrix display module that consists of LCD panel LCD-5021, LCD control driver HD44780, driver LC7930 and is capable of providing (16 characters x 2 lines) display. It contains a controller, a data RAM, and a character generator ROM required for providing display. Data interfacing is in 8-bit parallel or 4-bit parallel and data can be written in or read from a microprocessor.

General Specifications

- | | |
|--------------------------------|---|
| 1. Display stem | 1/5bias 1/16duty |
| 2. Display content | 16 character x 2 lines |
| 3. Dots organizing 1 character | 5 x 7 dots/character + cursor |
| 4. Display data RAM | 80 x 8 bits |
| 5. Character generator ROM | 160-character JIS font set + 32-character special font set
Refer to Table 1. |
| 6. Character generator RAM | 64 x 8 bits 5 x 7 dots 8 characters |
| 7. Instruction function | Refer to Table 2. |
| 8. Circuit diagram | Refer to Fig. 3 |

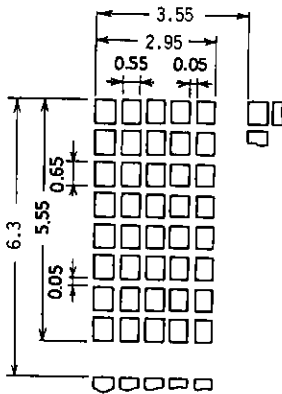
Outline

- | | |
|--------------------------------|--------------------------------|
| 1. Module outline | 32.6(W) x 85.0(L) x 10(T) (mm) |
| 2. View area | 60.5 x 14.4 (mm) |
| 3. Dot size | 0.55 x 0.65 (mm) |
| 4. Dot pitch | 0.60 x 0.70 (mm) |
| 5. Character size (5 x 8 dots) | 2.95 x 5.55 (mm) |

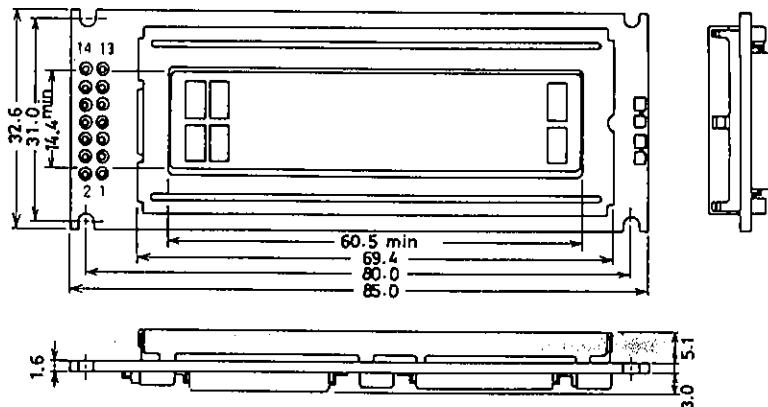
Absolute Maximum Ratings/Ta=25 °C

			unit
Supply Voltage	VDD-VSS	-0.3 to +7	V
Input Voltage	VI	-0.3 to VDD+0.3	V
Drive Voltage	VDD-VO	-0.3 to +9	V
Operating Temperature	Topr	0 to +50	°C
Storage Temperature	Tstg	-20 to +70	°C

Module Dimensions 5000A
(unit: mm)



Display Pattern

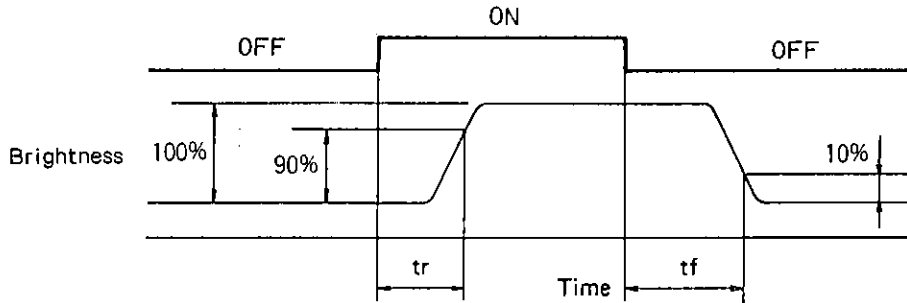


DM1620

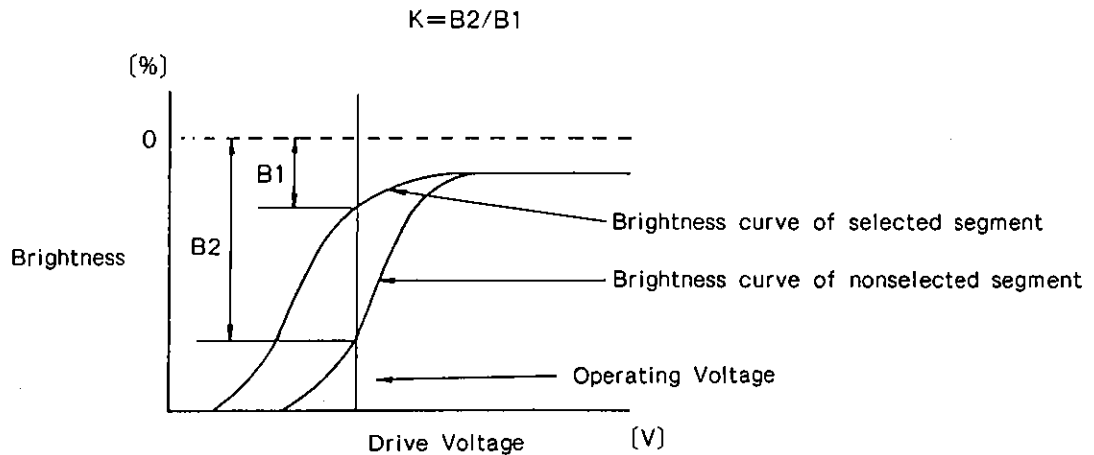
Electrooptical Characteristics/ $V_{DD}-V_{SS}=5.0V$, $T_a=25^\circ C$ unless otherwise specified

		min	typ	max	unit
Input "High" Voltage	V_{IH}	2.2		5.0	V
Input "Low" Voltage	V_{IL}	0		0.5	V
Output "High" Voltage	V_{OH} DB0 to DB7, $-I_{OH}=0.2mA$	2.4			V
Output "Low" Voltage	V_{OL} DB0 to DB7, $-I_{OL}=1.2mA$			0.4	V
Input Current	I_P Pull-up MOS $V_{DD}=5V$	50	125	250	μA
Current Dissipation	I_{DD} No input/output current included		(1.2)	2.5	mA
Oscillation Frequency	F_{OSC}	190	270	350	kHz
Viewing Angle	$\phi_2 - \phi_1$ $K=1.4$ $\theta=0^\circ$	20			degree
Contrast Ratio	K $\phi=20^\circ$ $\theta=0^\circ$	3.0			
Rise Time	t_r $\phi=20^\circ$ $\theta=0^\circ$		150	250	ms
Fall Time	t_f $\phi=20^\circ$ $\theta=0^\circ$		150	250	ms
LCD Drive Voltage	$V_{DD}-V_O$ $T_a=0^\circ C$ $\phi=20^\circ$, $\theta=0^\circ$, $K \geq 3$	4.4	4.5	4.6	V
(Recommend Value)	$V_{DD}-V_O$ $T_a=25^\circ C$ " " "	4.0	4.1	4.2	V
1/16 duty	$V_{DD}-V_O$ $T_a=50^\circ C$ " " "	3.4	3.5	3.6	V

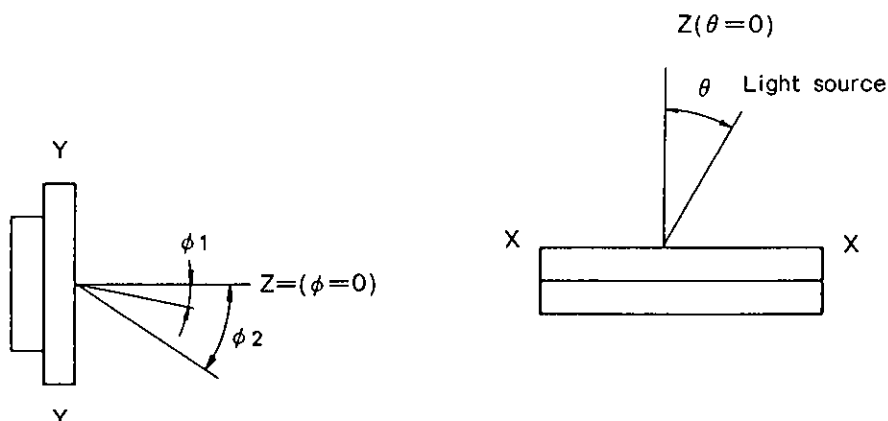
(1) Test Condition for Response Time (t_r, t_f)



(2) Definition of Contrast (K)



(3) Contrast Ratio Measuring Method



Angles ϕ and θ are defined shown above.

The light source is placed in the θ direction at an angle of 30° and the sensor is placed in the ϕ direction to measure the contrast.

Pin Description

No.	Pin Name	Function
1	VSS	(-) power supply pin 0V
2	VDD	(+) power supply pin +5V
3	V _O	Pin for applying LCD drive voltage
4	RS	Input pin HI=Data LOW=Instruction
5	R/W	Input pin HI=Read LOW=Write
6	E	Input pin Enable signal
7	DB0	} Data bus line
8	DB1	
9	DB2	
10	DB3	
11	DB4	
12	DB5	
13	DB6	
14	DB7	

Note 1. The LCD drive voltage can be varied from 3V to 5V by a variable resistor of 5kohm connected across VSS and V_O.

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Timing Characteristics

			min	typ	max	unit
Enable Cycle Time		t_{cycE}	1000			ns
Enable Pulse Width	High level	P_{WEH}	450			ns
Enable Rise/Fall time		t_{Er}, t_{Ef}			25	ns
Set Up Time	RS/RW-E	t_{As}	140			ns
Address Hold Time		t_{AH}	10			ns
Data Delay time		t_{DDR}			320	ns
Data Set Up Time		t_{DSW}	195			ns
Data Hold Time		$t_H(t_{DHR})$	10 (20)			ns

Figs. 1,2

Write Operation

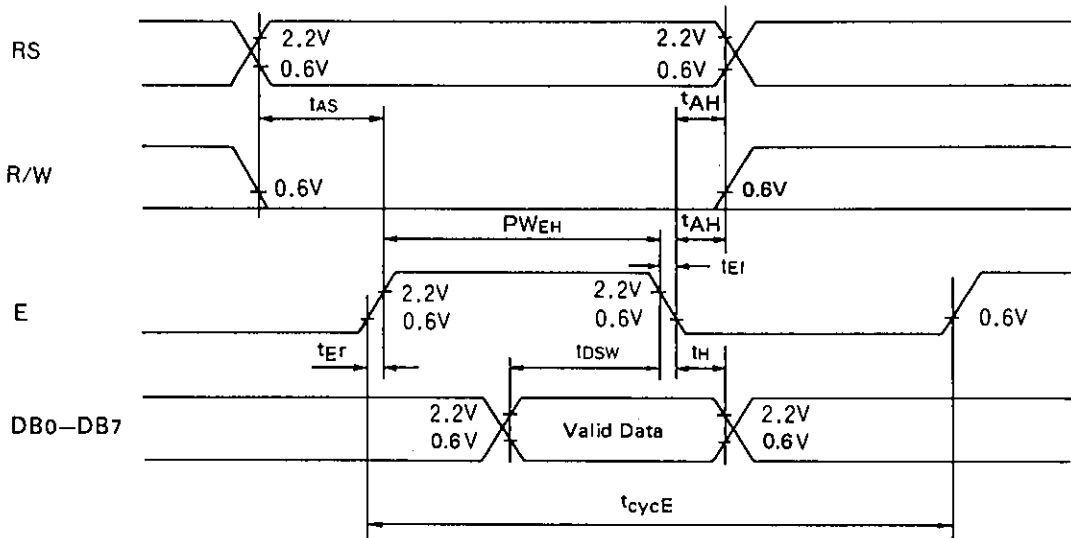


Fig. 1 Interface Timing (Data Write)

Read Operation

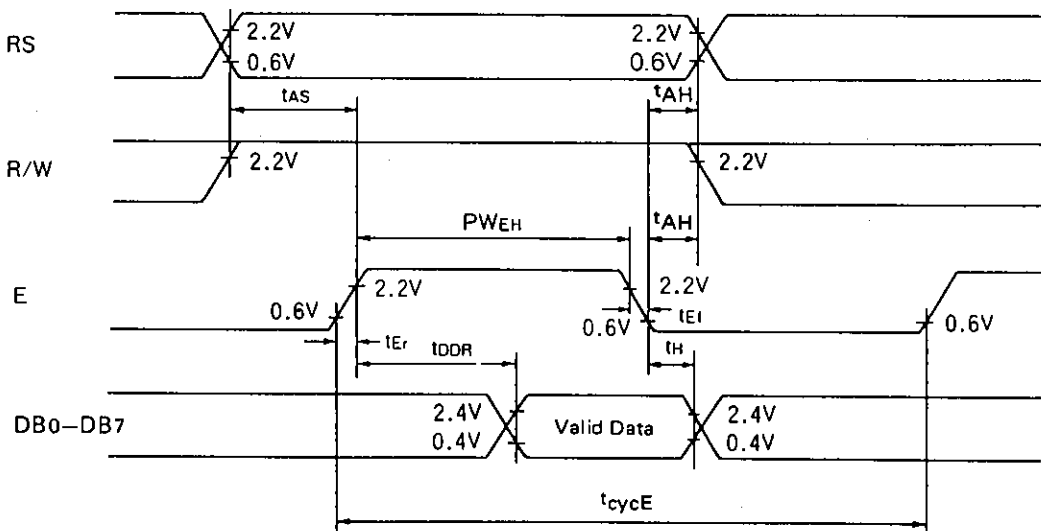


Fig. 2 Interface Timing (Data Read)

Table 1 Character code

Hi-order Low-order 4-bit 4-bit	0000	0010	0011	0100	0101	0110	0111	1010	1011	1100	1101	1110	1111
xxxx0000	CG RAM (1)		0	a	P	'	p	-	9	z	e	o	p
xxxx0001	(2)	!	l	A	O	a	q	u	7	9	4	5	q
xxxx0010	(3)	"	2	B	R	b	r	T	f	u	x	p	e
xxxx0011	(4)	#	3	C	S	c	s	J	o	t	e	s	e
xxxx0100	(5)	\$	4	D	T	d	t	\	T	t	P	p	a
xxxx0101	(6)	%	5	E	U	e	u	#	*	+	1	s	o
xxxx0110	(7)	&	6	F	V	f	v	9	n	=	a	p	z
xxxx0111	(8)	'	7	G	W	g	w	7	*	7	9	g	n
xxxx1000	(1)	(8	H	X	h	x	4	o	*	u	r	x
xxxx1001	(2))	9	I	Y	i	y	o	t	J	u	'	y
xxxx1010	(3)	*	#	J	Z	j	z	s	3	n	v	j	f
xxxx1011	(4)	+	;	K	L	k	l	!	*	7	o	*	n
xxxx1100	(5)	,	<	L	*	l	l	9	z	7	o	o	n
xxxx1101	(6)	-	=	M	I	m	i	3	z	\	o	t	+
xxxx1110	(7)	.	>	N	^	n	^	9	z	9	o	n	
xxxx1111	(8)	/	?	O	_	o	_	+	u	u	7	o	

(Note) The CG RAM is a character generator RAM used to store the character patterns that can be program-rewritten, as desired, by the user.

Table 2 Instruction function

Instruction	Code										Contents	Execution Time (f _{Osc} =250kHz)	
	RS	R/W	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0			
Display clear	0	0	0	0	0	0	0	0	0	1	Clears all display and returns the cursor to the home position (address 0).	82μs to 1.64ms	
Cursor home	0	0	0	0	0	0	0	0	0	1	*	Returns the cursor to the home position (address 0). Also returns the display being shifted to the original position. The DD RAM contents remain unaffected.	40 μs to 1.6ms
Entry mode set	0	0	0	0	0	0	0	0	1	I/D	S	Sets the cursor move direction and specified whether to or not to shift the display. These operations are performed during data write and read.	40μs
Display ON/OFF control	0	0	0	0	0	0	0	1	D	C	B	Sets all display ON/OFF(D), cursor ON/OFF(C), cursor position character blink(B).	40μs
Cursor/display shift	0	0	0	0	0	1	S/C	R/L	*	*	Moves the cursor and shifts the display without affecting the DD RAM contents.	40μs	
Function set	0	0	0	0	1	DL	N	F	*	*	Sets the interface data length (DL), number of display lines (L), and character font (F).	40μs	
CG RAM address set	0	0	0	1	ACG						Sets the CG RAM address. RAM data is sent/received after this setting.	40μs	
DD RAM address set	0	0	1	ADD						Sets the DD RAM address. DD RAM data is sent/received after this setting.	40μs		
Busy flag/address read	0	1	BF	AC						Reads the contents of busy flag (BF) indicating internal operation is in progress and reads the contents of address counter.	1μs		
CG RAM/DD RAM data write	1	0	Write Data						Writes data into the DD RAM or CG RAM.	40μs			
CG RAM/DD RAM data read	1	1	Read Data						Reads data from the DD RAM or CG RAM.	40μs			
	I/D = 1: Increment (+1) I/D = 0: Decrement (-) S = 1: Accompanied by display shift S/C = 1: Display shift S/C = 0: Cursor move R/L = 1: Right-shift R/L = 0: Left-shift DL = 1: 8 bits DL = 0: 4 bits N = 1: 2 lines N = 0: 1 line F = 1: 5 x 10 dots F = 0: 5 x 7 dots BF = 1: Internally operating BF = 0: Possible to accept instruction										DD RAM: Display data RAM CG RAM: Character generator RAM ACG: CG RAM address ADD: DD RAM address Corresponds to cursor address. AC: Address counter used for both DD RAM and CG RAM.	The change in the frequency (f _{Osc}) also causes the execution time to be changed. (Example) When f _{Osc} =270kHz, 40μs x 250/270 = 37μs.	

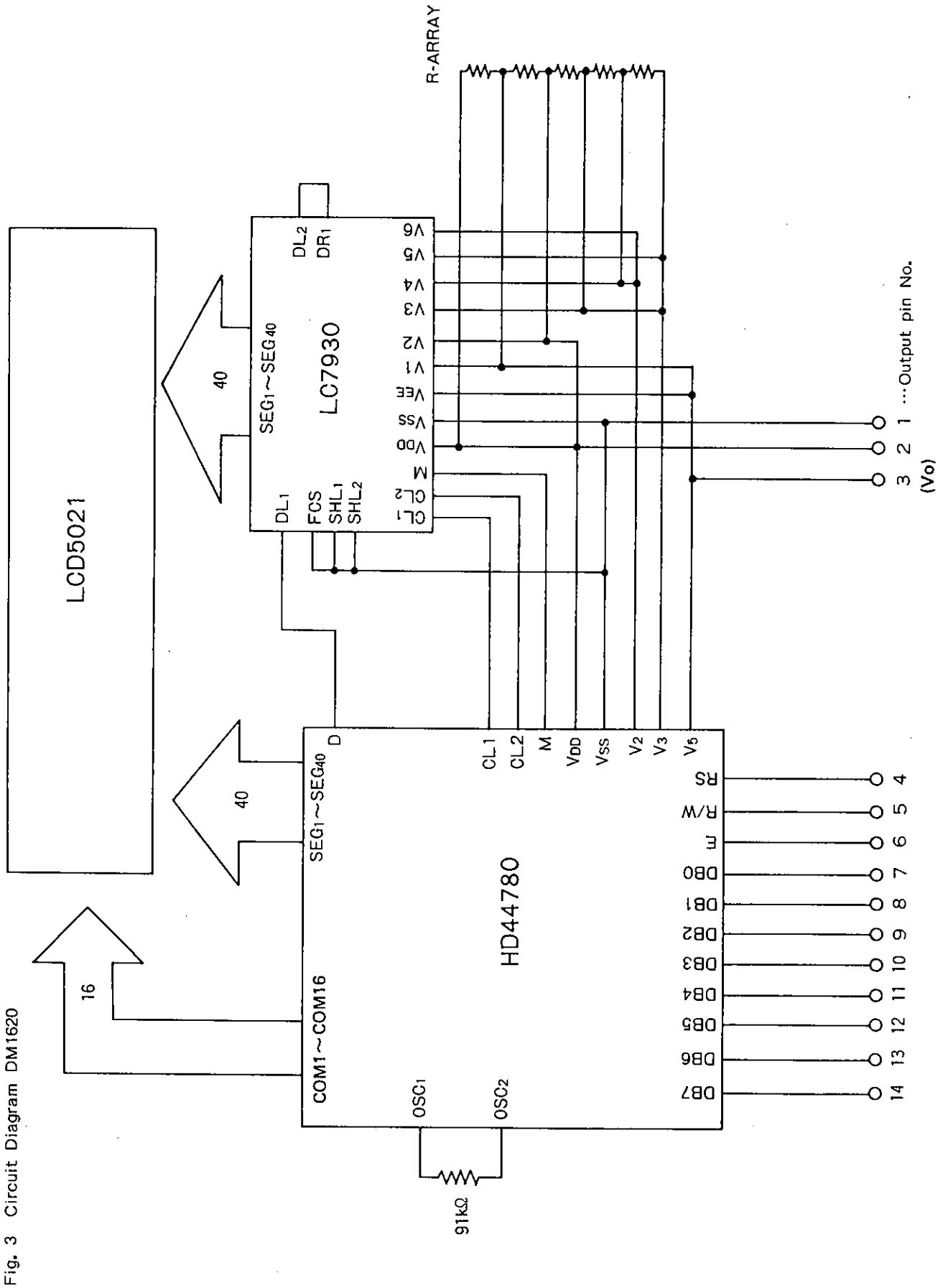


Fig. 3 Circuit Diagram DM1620